Diode Semiconductor Device - Page 1 of 1



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GI	ass
0 ۱	verall Length:
	etween 0.220 inches and 0.260 inches
Те	erminal Length:
Be	etween 1.000 inches and 1.620 inches
0 ١	verall Diameter:
0.4	400 inches
Fu	Inction For Which Designed:
Re	ectifier
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
Do	p-3
Mo	ounting Method:
Те	erminal
Fe	eatures Provided:
He	ermetically sealed case
Se	emiconductor Material:
Sil	licon
Vc	oltage Rating In Volts Per Characteristic:
10	00.0 repetitive peak reverse voltage
Сι	urrent Rating Per Characteristic:
60	0.00 milliamperes average forward current averaged over a full 60-hz cycle
Ma	aximum Operating Tempurature Per Measurement Point:
11	5.0 degrees celsius ambient air
Те	erminal Type And Quantity:
2 ι	uninsulated wire lead
Sł	nelf Life:
N/	a
Ur	nit Of Measure:
De	emilitarization:
No	
Fii	ig:
A1	10a0